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# 4V Drive Nch+Pch MOSFET

## SH8M2

### ●Structure

Silicon N-channel / P-channel MOSFET

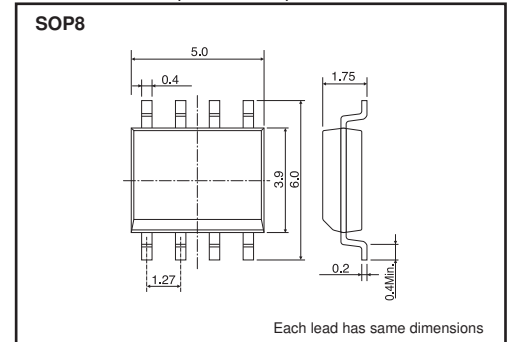
### ●Features

- 1) Low on-resistance.
- 2) Built-in G-S protection diode.
- 3) Small surface mount package (SOP8).

### ●Application

Power switching, DC / DC converter.

### ●Dimensions (Unit : mm)



### ●Packaging specifications

Type	Package	Taping
	Code	TB
	Basic ordering unit (pieces)	2500
SH8M2		○

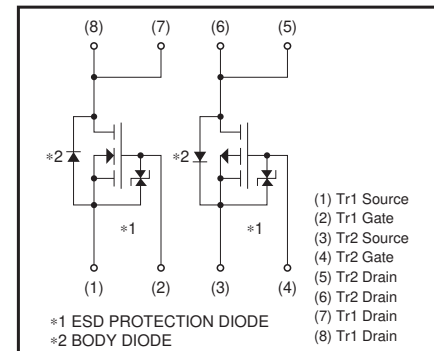
### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
		Tr1 : N-ch	Tr2 : P-ch	
Drain-source voltage	$V_{DSS}$	30	-30	V
Gate-source voltage	$V_{GSS}$	±20	±20	V
Drain current	Continuous	$I_D$	±3.5	A
	Pulsed	$I_{DP}^{*1}$	±14	A
Source current (Body diode)	Continuous	$I_S$	1.6	A
	Pulsed	$I_{SP}^{*1}$	14	A
Total power dissipation	$P_D^{*2}$	2.0		W / TOTAL
Channel temperature	$T_{ch}$	150		°C
Storage temperature	$T_{stg}$	-55 to +150		°C

\*1  $P_w \leq 10 \mu s$ , Duty cycle  $\leq 1\%$

\*2 Mounted on a ceramic board.

### ●Inner circuit



## N-ch

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	–	–	±10	μA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	30	–	–	V	I <sub>D</sub> = 1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	–	–	1	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	1.0	–	2.5	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA
Static drain-source on-state resistance	R <sub>DS(on)*</sub>	–	59	83	mΩ	I <sub>D</sub> = 3.5A, V <sub>GS</sub> = 10V
		–	93	130	mΩ	I <sub>D</sub> = 3.5A, V <sub>GS</sub> = 4.5V
		–	107	150	mΩ	I <sub>D</sub> = 3.5A, V <sub>GS</sub> = 4V
Forward transfer admittance	Y <sub>fs</sub>   *	2.0	–	–	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 3.5A
Input capacitance	C <sub>iss</sub>	–	140	–	pF	V <sub>DS</sub> = 10V
Output capacitance	C <sub>oss</sub>	–	45	–	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	–	30	–	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	–	6	–	ns	V <sub>DD</sub> = 15V I <sub>D</sub> = 1.75A
Rise time	t <sub>r</sub> *	–	6	–	ns	V <sub>GS</sub> = 10V
Turn-off delay time	t <sub>d(off)</sub> *	–	17	–	ns	R <sub>L</sub> = 8.57Ω
Fall time	t <sub>f</sub> *	–	4	–	ns	R <sub>G</sub> =10Ω
Total gate charge	Q <sub>g</sub> *	–	2.5	3.5	nC	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 5V
Gate-source charge	Q <sub>gs</sub> *	–	0.8	–	nC	I <sub>D</sub> = 3.5A
Gate-drain charge	Q <sub>gd</sub> *	–	0.8	–	nC	R <sub>L</sub> = 4.29Ω, R <sub>G</sub> = 10Ω

\*Pulsed

## ●Body diode characteristics (Source-Drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V <sub>SD</sub> *	–	–	1.2	V	I <sub>S</sub> = 6.4A, V <sub>GS</sub> =0V

\*Pulsed

## P-ch

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-30	-	-	V	$I_D = -1mA, V_{GS} = 0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	-1	$\mu A$	$V_{DS} = -30V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	-1.0	-	-2.5	V	$V_{DS} = -10V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	-	65	90	$m\Omega$	$I_D = -3.5A, V_{GS} = -10V$
		-	100	140	$m\Omega$	$I_D = -1.75A, V_{GS} = -4.5V$
		-	120	165	$m\Omega$	$I_D = -1.75A, V_{GS} = -4V$
Forward transfer admittance	$ Y_{fs} $ *	1.8	-	-	S	$V_{DS} = -10V, I_D = -1.75A$
Input capacitance	$C_{iss}$	-	490	-	pF	$V_{DS} = -10V$
Output capacitance	$C_{oss}$	-	110	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	$C_{rss}$	-	75	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$ *	-	10	-	ns	$V_{DD} = -15V$ $I_D = -1.75A$
Rise time	$t_r$ *	-	15	-	ns	$V_{GS} = -10V$
Turn-off delay time	$t_{d(off)}$ *	-	35	-	ns	$R_L = 8.57\Omega$
Fall time	$t_f$ *	-	10	-	ns	$R_G = 10\Omega$
Total gate charge	$Q_g$ *	-	5.5	7.7	nC	$V_{DD} = -15V, V_{GS} = -5V$
Gate-source charge	$Q_{gs}$ *	-	1.5	-	nC	$I_D = -3.5A$
Gate-drain charge	$Q_{gd}$ *	-	2.0	-	nC	$R_L = 4.29\Omega, R_G = 10\Omega$

\*Pulsed

## ●Body diode characteristics (Source-Drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_{SD}$ *	-	-	-1.2	V	$I_S = -1.6A, V_{GS} = 0V$

\*Pulsed

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